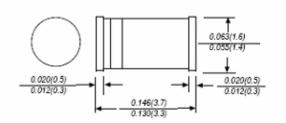


Technical Data Data Sheet N0200, Rev. A **Green Products**

BZV55C/ZMM55C-SERIES ZENER DIODES

Zener Voltage: 2.4-180V Peak Pulse Power: 500mW

MINI MELF



FEATURE

- Low zener impedance
- Low regulation factor
- · Glass passivated junction
- High temperature soldering guaranteed: 260°C/10S at terminals
- ◆ This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

MECHANICAL DATA

Case: MINI MELF molded glass body

Terminals: Plated axial leads, solderable per MIL-STD 750,

method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any Weight: 0.002 ounce, 0.05 gram

Marking: Part Name, SSG and Date Code

ORDERING INFORMATION

Device	Package	Shipping
BZV55C/ZMM55C-SERIES	MELF (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	VALUE	UNITS
Zener Current see Table Characteristics			
Power Dissipation at Tamb=25℃(Note 1)	P∞	500	mW
Junction Temperature	Tj	200	°C
Storage Temperature Range	Тьта	-65 to + 200	°C
Thermal resistance junction ambient(Note 1)	R _{8M}	0.3	K/mW
Forward voltage at IF=100mA	V _F	1.0	٧

Note 1: Valid provided that leads at a distance of 10mm from case are kept at ambient temperature

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ELECTRICAL CHARACTERISTICS (at TA=25℃ unless otherwise noted)

Device Type	Zener\	Nominal ZenerVoltage Vz@lzт		Maximum Zener Impedance		Maximum Reverse Leakage Current		Typical Temperature	Maximum Regulator Current	
201100 1,700	`	9121	lzт	Zzt@lzt	Zzk@lzk	Izĸ	IR	@Vr	Coefficient	Izm
	Min	Max	mA	Ohms	Ohms	mA	μΑ	Volts	(%/°C)	mA
BZV/ZMM55C2V4	2.28	2.56	5.0	85	600	1.0	50	1.0	-0.085	155
BZV/ZMM55C2V7	2.5	2.9	5.0	85	600	1.0	10	1.0	-0.080	135
BZV/ZMM55C3V0	2.8	3.2	5.0	85	600	1.0	4.0	1.0	-0.075	125
BZV/ZMM55C3V3	3.1	3.5	5.0	85	600	1.0	2.0	1.0	-0.070	115
BZV/ZMM55C3V6	3.4	3.8	5.0	85	600	1.0	2.0	1.0	-0.065	105
BZV/ZMM55C3V9	3.7	4.1	5.0	85	600	1.0	2.0	1.0	-0.060	95
BZV/ZMM55C4C3	4.0	4.6	5.0	75	600	1.0	1.0	1.0	±0.055	90
BZV/ZMM55C4V7	4.4	5.0	5.0	60	600	1.0	0.5	1.0	±0.030	85
BZV/ZMM55C5V1	4.8	5.4	5.0	35	550	1.0	0.1	1.0	±0.030	80
BZV/ZMM55C5V6	5.2	6.0	5.0	25	450	1.0	0.1	1.0	+0.038	70
BZV/ZMM55C6V2	5.8	6.6	5.0	10	200	1.0	0.1	2.0	+0.045	64
BZV/ZMM55C6V8	6.4	7.2	5.0	8	150	1.0	0.1	3.0	+0.050	58
BZV/ZMM55C7V5	7.0	7.9	5.0	7	50	1.0	0.1	5.0	+0.058	53
BZV/ZMM55C8V2	7.7	8.7	5.0	7	50	1.0	0.1	6.2	+0.062	74
BZV/ZMM55C9V1	8.5	9.6	5.0	10	50	1.0	0.1	6.8	+0.068	43
BZV/ZMM55C10	9.4	10.6	5.0	15	70	1.0	0.1	7.5	+0.075	40
BZV/ZMM55C11	10.4	11.6	5.0	20	70	1.0	0.1	8.2	+0.076	36
BZV/ZMM55C12	11.4	12.7	5.0	20	90	1.0	0.1	9.1	+0.077	32
BZV/ZMM55C13	12.4	14.1	5.0	26	110	1.0	0.1	10	+0.079	29
BZV/ZMM55C15	13.8	15.6	5.0	30	110	1.0	0.1	11	+0.082	27
BZV/ZMM55C16	15.3	17.1	5.0	40	170	1.0	0.1	12	+0.083	24
BZV/ZMM55C18	16.8	19.1	5.0	50	170	1.0	0.1	13	+0.085	21
BZV/ZMM55C20	18.8	21.2	5.0	55	220	1.0	0.1	15	+0.086	20
BZV/ZMM55C22	20.8	23.3	5.0	55	220	1.0	0.1	16	+0.087	18
BZV/ZMM55C24	22.8	25.6	5.0	80	220	1.0	0.1	18	+0.088	16
BZV/ZMM55C27	25.1	28.9	5.0	80	220	1.0	0.1	20	+0.090	14
BZV/ZMM55C30	28	32	5.0	80	220	1.0	0.1	22	+0.091	13
BZV/ZMM55C33	31	35	5.0	80	220	1.0	0.1	24	+0.092	12
BZV/ZMM55C36	34	38	5.0	80	220	1.0	0.1	27	+0.093	11
BZV/ZMM55C39	37	41	2.5	90	500	0.5	0.1	30	+0.094	10
BZV/ZMM55C43	40	46	2.5	90	600	0.5	0.1	33	+0.095	9.2
BZV/ZMM55C47	44	50	2.5	110	700	0.5	0.1	36	+0.095	8.5
BZV/ZMM55C51	48	54	2.5	125	700	0.5	0.1	39	+0.096	7.8
BZV/ZMM55C56	52	60	2.5	135	1000	0.5	0.1	43	+0.096	7.0
BZV/ZMM55C62	58	66	2.5	150	1000	0.5	0.1	47	+0.096	6.4
BZV/ZMM55C68	64	72	2.5	200	1000	0.5	0.1	51	+0.096	5.9
BZV/ZMM55C75	70	80	2.5	250	1500	0.5	0.1	56	+0.096	5.3
BZV/ZMM55C82	77	87	2.5	300	2000	0.5	0.1	62	+0.096	4.8
BZV/ZMM55C91	85	96	1.0	450	5000	0.1	0.1	68	+0.096	4.4
BZV/ZMM55C100	94	106	1.0	450	5000	0.1	0.1	75	+0.096	4.0
BZV/ZMM55C110	104	116	1.0	600	5000	0.1	0.1	82	+0.096	3.6
BZV/ZMM55C120	114	127	1.0	800	5000	0.1	0.1	91	+0.096	3.3
BZV/ZMM55C130	124	141	1.0	1000	5000	0.1	0.1	100	+0.096	3.0
BZV/ZMM55C150	138	156	1.0	1200	5000	0.1	0.1	110	+0.096	2.6
BZV/ZMM55C160	153	171	1.0	1500	5000	0.1	0.1	120	+0.096	2.5
BZV/ZMM55C180	168	191	1.0	1800	5000	0.1	0.1	130	+0.096	2.2
BZV/ZMM55C188	188	212	1.0	2000	5000	0.1	0.1	150	+0.096	2.0

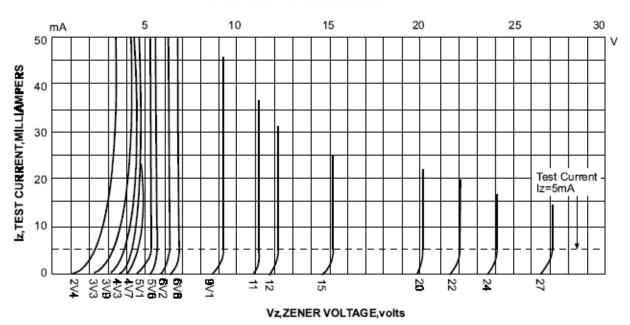
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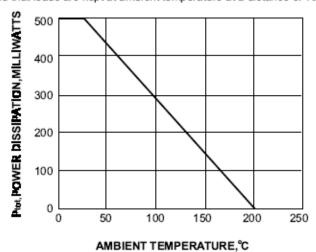
Technical Data Data Sheet N0200, Rev. A **Green Products**

RATINGS AND CHARACTERISTIC CURVES BZV/ZMM55-SERIES

Breakdown characteristics



Admissible power dissipation versus ambient temperature Valid provided that leads are kept at ambient temperature at a distance of 10mm from case



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BZV55C-SERIES

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Green Products

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